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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/620,054	07/14/2003	Zhongze Wang	2269-3541.3US (97-0855.03	7663
24247 7.	590 11/19/2004		EXAM	INER
TRASK BRIT		ESTRADA, MICHELLE		
P.O. BOX 2550 SALT LAKE O	CITY, UT 84110		ART UNIT	PAPER NUMBER
	,		2823	
			DATE MAILED: 11/19/200	4

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)
Office Action Summary	10/620,054	WANG ET AL.
Office Action Summary	Examiner	Art Unit
	Michelle Estrada	2823
The MAILING DATE of this communication for Reply	on appears on the cover sneet w	ith the correspondence address
A SHORTENED STATUTORY PERIOD FOR THE MAILING DATE OF THIS COMMUNICATORY Extensions of time may be available under the provisions of 37 after SIX (6) MONTHS from the mailing date of this communicator of the proiod for reply specified above is less than thirty (30) dayon of the proiod for reply is specified above, the maximum statutor and the properties of the properties of the proiod for reply within the set or extended period for reply will, the properties of the properties o	TION.  CFR 1.136(a). In no event, however, may a stion.  ys, a reply within the statutory minimum of thir y period will apply and will expire SIX (6) MON by statute, cause the application to become Al	reply be timely filed ty (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).
atus	•	
1) Responsive to communication(s) filed or	n 16 August 2004.	
· _ ·	This action is non-final.	
·3)☐ Since this application is in condition for a		ters, prosecution as to the merits is
closed in accordance with the practice u		
sposition of Claims		
4)⊠ Claim(s) <u>1-12 and 14-29</u> is/are pending	in the application	
4a) Of the above claim(s) is/are w		
5) Claim(s) is/are allowed.		
6)⊠ Claim(s) <u>1-5 and 14-22</u> is/are rejected.		
7) Claim(s) 6-12 and 23-29 is/are objected	to.	
8) Claim(s) are subject to restriction	and/or election requirement.	
oplication Papers		
9) The specification is objected to by the Ex	kaminer.	
10) The drawing(s) filed on is/are: a)[	_	by the Examiner.
Applicant may not request that any objection	to the drawing(s) be held in abeya	nce. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the	correction is required if the drawing	(s) is objected to. See 37 CFR 1.121(d).
11) The oath or declaration is objected to by	the Examiner. Note the attache	d Office Action or form PTO-152.
iority under 35 U.S.C. § 119		
i2) Acknowledgment is made of a claim for f a) All b) Some * c) None of:	oreign priority under 35 U.S.C. {	§ 119(a)-(d) or (f).
1. Certified copies of the priority doc	·	
2. Certified copies of the priority doc		
3. Copies of the certified copies of the	•	received in this National Stage
application from the International	Bureau (PCT Rule 17.2(a)).	
* See the attached detailed Office action fo		and a state of the

U.S. Patent and Trademark Office PTOL-326 (Rev. 1-04)

1) Notice of References Cited (PTO-892)

Paper No(s)/Mail Date \_

2) Notice of Draftsperson's Patent Drawing Review (PTO-948)

3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)

4) Interview Summary (PTO-413)
Paper No(s)/Mail Date. \_\_\_\_\_.

6) Other: \_\_

5) Notice of Informal Patent Application (PTO-152)

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#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-5 and 14-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Komenaka (5,914,524) in view of Endo et al. (5,990,537).

With respect to claim 1, Komenaka discloses an insulating substrate (41); a refractory metal nitride layer (102) disposed above the insulating substrate; a conductive layer (101) disposed over the refractory metal nitride layer.

Komenaka et al. do not disclose that the conductive layer is a tungsten silicide layer.

With respect to claims 1 and 22, Endo et al. discloses that the fuse may be made of a tungsten silicide layer (Col. 4, lines 37-40).

It would have been within the scope of one of ordinary skill in the art to combine the teachings of Komenaka and Endo et al. to enable the material of the conductive layer of Endo et al. to be used in the process of Komenaka et al. because one of ordinary skill in the art would have been motivated to look to alternative suitable materials to be used in the disclosed conductive layer of Komenaka et al. and art recognized suitability for an intended purpose has been recognized to be motivation to combine. See MPEP 2144.07. Furthermore, it would have been within the scope of

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one of ordinary skill in the art to form the fuse in an isolation region to electrically isolate the active regions.

With respect to claims 2 and 15, Endo et al. discloses wherein the insulating substrate is an isolation region (34), it would have been within the scope of one of ordinary skill in the art to form the fuse in an isolation region to electrically isolate the active regions.

With respect to claims 3 and 16, Endo et al. discloses wherein the isolation region is a field oxide region (36).

With respect to claim 4 and 17, Endo et al. discloses wherein the field oxide region is disposed on a semiconductor substrate (31).

With respect to claim 5 and 18, Endo et al. discloses wherein the semiconductor substrate is a silicon wafer (Col. 4, lines 4-20).

With respect to claim 14, Komenaka discloses an insulating substrate (41); a refractory metal nitride layer (102) disposed above the insulating substrate; a conductive layer (101) disposed over the refractory metal nitride layer.

With respect to claim 19, Komenaka discloses wherein the refractory metal nitride layer includes titanium.

With respect to claim 20, Komenaka discloses wherein the refractory metal nitride layer comprises titanium nitride.

With respect to claim 21, Komenaka discloses wherein the conductive layer is a metal (Col. 6, lines 1-24).

## Allowable Subject Matter

Claims 6-12 and 23-29 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

## Response to Arguments

Applicant's arguments filed 8/16/04 have been fully considered but they are not persuasive. Applicant argues that Komenaka et al. do not disclose a silicide layer disposed over the refractory metal nitride layer as amended claim 14. However, the Examiner presents a new ground of rejection necessitated by the amendment to claim 14, thus Endo et al. disclose that tungsten silicide is a suitable material for a fuse.

Applicant argues that Komenaka et al. do not disclose a tungsten silicide layer disposed over the refractory metal nitride layer as recited claim 1. However, Komenaka et al. was not relied on upon for that purpose. Endo et al. was relied on for the teaching that a tungsten silicide is a suitable material for a fuse.

Applicant argues that in Endo et al. neither the metal guard ring 41B, the passivation layer 38 not the nitride 39 are formed over or part of the fuse. However, the additional teachings of Endo et al. do not render invalid the teaching relied on, which is that tungsten silicide is a suitable material for a fuse.

Applicant argues that Endo et al. do not disclose that the fuse a tungsten silicide layer is disposed over the refractory metal nitride. However, Endo et al. was not relied

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on upon for that purpose. Komenaka et al. was relied on to teach a fuse layer over a

refractory metal nitride.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in

this Office action. Accordingly, THIS ACTION IS MADE FINAL.

§ 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37

CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE

MONTHS from the mailing date of this action. In the event a first reply is filed within

TWO MONTHS of the mailing date of this final action and the advisory action is not

mailed until after the end of the THREE-MONTH shortened statutory period, then the

shortened statutory period will expire on the date the advisory action is mailed, and any

extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

the advisory action. In no event, however, will the statutory period for reply expire later

than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Michelle Estrada whose telephone number is 571-272-

1858. The examiner can normally be reached on Monday through Friday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Olik Chaudhuri can be reached on 571-272-1855. The fax phone number

for the organization where this application or proceeding is assigned is 703-872-9306.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is 571-272-

2800.

Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only.

For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

George Fourson
Primary Examiner

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MEstrada

November 2, 2004